# MAPRST1214-6UF



Radar Pulsed Power Transistor 6W, 1.2-1.4 GHz, 6ms Pulse, 25% Duty

M/A-COM Products Released, 30 May 07

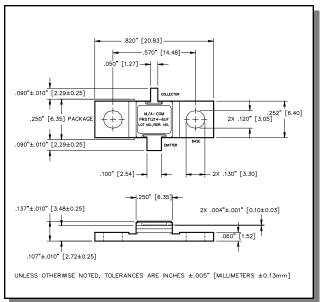
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	65	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	I <sub>C</sub>	1.9	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	100	W
Storage Temperature	$T_{STG}$	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



#### Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	65	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	3.0	mA
Thermal Resistance	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	1.8	°C/W
Output Power	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	6	-	W
Power Gain	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	$G_P$	8.75	-	dB
Gain Flatness	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	ΔG	-	0.75	dB
Collector Efficiency	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	ης	40	-	%
Input Return Loss	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	RL	-	-10	dB
Pulse Droop	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	Droop	-	0.3	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 0.8W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

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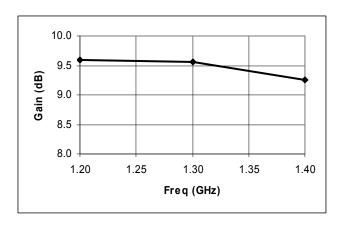


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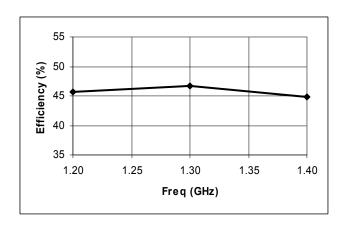
#### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	Droop (dB)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	0.8	7.3	9.59	0.44	45.7	0.10	-14.1	S	Р
1.3	0.8	7.2	9.56	0.43	46.6	0.09	-15.2	S	Р
1.4	0.8	6.7	9.26	0.42	44.8	0.08	-16.1	S	Р

### Gain vs. Frequency

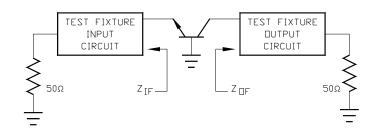


#### Collector Efficiency vs. Frequency



#### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	$Z_{OF}(\Omega)$
1.2	3.7 – j 3.2	16.9 + j18.0
1.3	3.8 – j 3.4	14.2 + j16.4
1.4	3.4 – j 3.7	11.7 + j18.2



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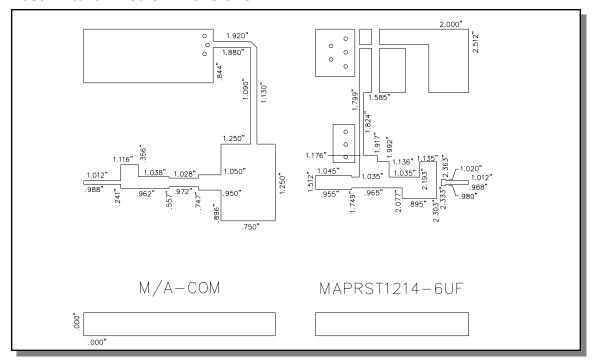
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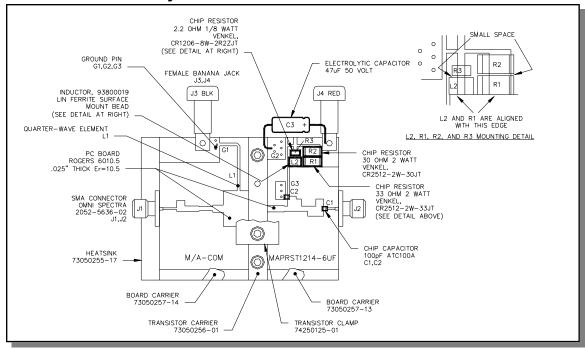


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#### **Test Fixture Circuit Dimensions**



### **Test Fixture Assembly**



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